

L Number	Hits	Search Text	DB	Time stamp
-	25	(strain\$3 same (porous near5 crystal\$5)) and light	USPAT; US-PGPUB	2004/06/23 16:55
-	27	(strain\$3 same (porous near5 crystal\$5)) and (light radiation)	USPAT; US-PGPUB	2004/06/23 17:04
-	1887	(359/299,244,290,321,824).ccls. (310/311).ccls.	USPAT; US-PGPUB	2004/06/23 17:04
-	19	((359/299,244,290,321,824).ccls. (310/311).ccls.) and ((light radiation) with strain\$3)	USPAT; US-PGPUB	2004/06/23 17:11
-	19	((359/299,244,290,321,824).ccls. (310/311).ccls.) and ((light radiation) with strain\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:12
-	8820	((light radiation) with strain\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:13
-	15	((light radiation) with strain\$3) and (porous near5 crystal\$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:15
-	23	((light radiation) with strain\$3) and (porous near5 (silicon si))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:15
-	12	((light radiation) with strain\$3) and (porous near5 (silicon si)) not (((light radiation) with strain\$3) and (porous near5 crystal\$5))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:17
-	526	piezooptic\$2 or (piezo near2 optic\$2)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:18
-	263	(piezooptic\$2 or (piezo near2 optic\$2)) and crystal\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:18
-	112	((piezooptic\$2 or (piezo near2 optic\$2)) and crystal\$5) and strain\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:19
-	7	((piezooptic\$2 or (piezo near2 optic\$2)) and crystal\$5) and strain\$3) and porous	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:23
-	4	(US-5569626-\$ or US-5405786-\$ or US-5387803-\$ or US-5376818-\$).did.	USPAT	2004/06/23 17:22
-	4	((US-5569626-\$ or US-5405786-\$ or US-5387803-\$ or US-5376818-\$).did.) and (strain\$3 same (light radiation))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:25

-	437	438/57.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:25
-	32	438/57.ccls. and strain\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:25
-	14	438/57.ccls. and (strain\$3 same (light radiation))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:26
-	14	(438/57.ccls. and (strain\$3 same (light radiation))) and (crystal\$5 silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:26
-	1	((438/57.ccls. and (strain\$3 same (light radiation))) and (crystal\$5 silicon)) and porous	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:26
-	10	4524294.URPN.	USPAT	2004/06/23 17:56
-	16966	ferroelectric	USPAT; US-PGPUB	2004/06/23 17:58
-	166	ferroelectric same porous	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 18:02
-	40	(ferroelectric same porous) same crystal\$8	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 18:01
-	1092	(cadmium near2 sulfide) same crystal\$8	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 18:01
-	621	(cadmium near2 sulfide) with crystal\$8	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 18:01
-	2	(cadmium near2 sulfide) with (porous with crystal\$8)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 18:01
-	104	ferroelectric with porous	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 18:02
-	10	ferroelectric with porous with crystal\$8	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 18:02

-	2053785	porous (silicon crystal\$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:30
-	7577	porous adj2 (silicon crystal\$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:31
-	5227	porous adj2 (silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:31
-	4524	porous adj (silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:31
-	606	(porous adj (silicon)) same light	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:31
-	445	(porous adj (silicon)) with light	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:40
-	39807	ferroelectric\$2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:40
-	619	ferroelectric\$2 and (remanent near3 polariz\$8)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:41
-	1	(ferroelectric\$2 and (remanent near3 polariz\$8)) and (length with depend\$3 with photoelectric with effect)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:41
-	1	(ferroelectric\$2 and (remanent near3 polariz\$8)) and (photoelectric with effect)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:42
-	1	(ferroelectric\$2 and (remanent near3 polariz\$8)) and (photoelectric\$2 with effect)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:42
-	323	piezooptic\$2 or (piezo adj2 optic\$2)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 16:28
-	14	(piezooptic\$2 or (piezo adj2 optic\$2)) and porous	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 16:28

-	7	(piezooptic\$2 or (piezo adj2 optic\$2)) and (porous with (silicon or crystal\$5))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 16:28
-	7	((piezooptic\$2 or (piezo adj2 optic\$2)) and (porous with (silicon or crystal\$5))) and light	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 16:29